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MEMC 00-1400(2806.1)
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster et al.

Serial No. 10/039,196

Filed January 2, 2002

Confirmation No. 7221

For PROCESS FOR PREPARING SINGLE CRYSTAL SILICON HAVING
IMPROVED GATE OXIDE INTEGRITY

Examiner Benjamin L. Utech

Art Unit 1765

OCT 24 2002

October 18, 2002

TO THE COMMISSIONER OF PATENTS AND TRADEMARKS,

SIR:

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

In accordance with 37 C.F.R. 1.97 and 1.98 and MPEP 609, and in compliance with the duty of disclosure set forth in 37 C.F.R. 1.56, applicants submit copies of the references listed on the attached PTO/SB/08A for consideration by the Patent and Trademark Office in the above-entitled application and to be made of record therein.

This Information Disclosure Statement is being submitted pursuant to 37 C.F.R. 1.97(b) in that Applicant believes that it is being filed before the mailing date of the first Office action on the merits. Accordingly, neither a statement nor fee under 37 C.F.R. 1.97(c) is required. If Applicant is mistaken, and the mailing date of the first Office action on the merits precedes the filing of this Information Disclosure Statement, Applicant authorizes the Commissioner to charge the fee due under 37 C.F.R. 1.17(p) to Deposit Account No. 19-1345.

Respectfully submitted,

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OCT 2 2002

PTO/SB/08A				<i>Complete if Known</i>	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Application Number	10/039,186
				Filing Date	January 2, 2002
				Confirmation Number	7221
				First Named Inventor	Robert J. Falster
				Group Art Unit	1765
				Examiner Name	Benjamin L. Utech
Sheet	1	of	1	Attorney Docket No.	MEMC 00-1400(2806.1)

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code ² (if known)		
	15	5,502,010		Nadahara et al.	03-26-1996

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T ⁶
		Office	Number ⁴	Kind Code ² (if known)			
	16	WO	98/45507	A1	MEMC Electronic Materials, Inc.	10-15-1998	
	17	WO	00/00675	A1	MEMC Electronic Materials, Inc.	01-06-2000	

OTHER ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ⁶
	18	Partial International Search for analogous PCT application Serial No. PCT/US02/01127 dated September 9, 2002.			

Examiner Signature	Date Considered
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*EXAMINER Initial if reference considered, whether or not citation is in conformance with MPEP 609 Draw line through citation if not in conformance and not considered
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¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST 31). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached or place an "A" here if English language abstract is attached

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